

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Haupt Docket No.: 2003 P 51718 US
Serial No.: 10/766,053 Art Unit: 2822
Filed: January 28, 2004 Examiner: Tran, Thanh Y.
For: Method for N⁺ Doping of Amorphous Silicon and Polysilicon Electrodes
in Deep Trenches

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Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

AMENDMENT

Dear Sir:

Applicant respectfully submits the following amendments and remarks in response to Examiner's Office Action dated September 11, 2007. Applicant respectfully requests that these amendments and remarks be entered and the application be allowed.